

自主封測 品質把控 售後保障

WEB | WWW.TDSEMIC.COM



電源管理



顯示驅動



二三極管



LDO穩壓器



觸摸芯片



MOS管



運算放大器



存儲芯片



MCU



串口通信

PESD3V3L1BA

產品規格說明書

Bi-direction ESD Protection Diode

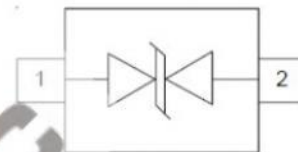
Features

- ◇ 150W (8x20us) Peak Pulse Power ◇
- Low Clamping Voltage
- ◇ SOD-323 Package
- ◇ RoHS Compliant
- ◇ Matte Tin Lead finish (Pb-Free) ◇
- Protect One I/O or Power Line
- ◇ Meet IEC61000-4-2 Level 4:
 - Contact Discharge > 25kV
 - Air Discharge > 25kV

Circuit Diagram



PIN Diagram



Applications

- ◇ Smart Phones
- ◇ Laptop Computers
- ◇ Portable Electronics

Ordering information

Device	Package	MARKING	Qty / Reel
PESD3V3L1BA	SOD-323	AB	3000

MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
IEC 61000-4-2 ESD Voltage	$V_{\text{ESD}}^{(1)}$	± 25	kV
Air Model			
Contact Model		± 25	
JESD22-A114-B ESD Voltage		± 16	
ESD Voltage	Machine Model	± 0.4	
Peak Pulse Power	$P_{\text{PP}}^{(2)}$	150	W
Peak Pulse Current	$I_{\text{PP}}^{(2)}$	10	A
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	$^{\circ}\text{C}$
Junction Temperature	T_j	150	$^{\circ}\text{C}$
Storage Temperature Range	T_{stg}	-55 ~ +150	$^{\circ}\text{C}$

(1).Device stressed with ten non-repetitive ESD pulses.

(2).Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5.

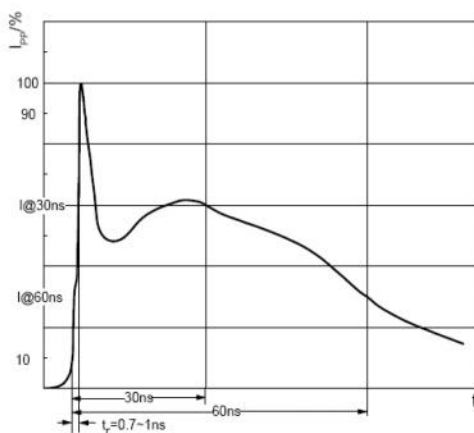
ESD standards compliance

IEC61000-4-2 Standard

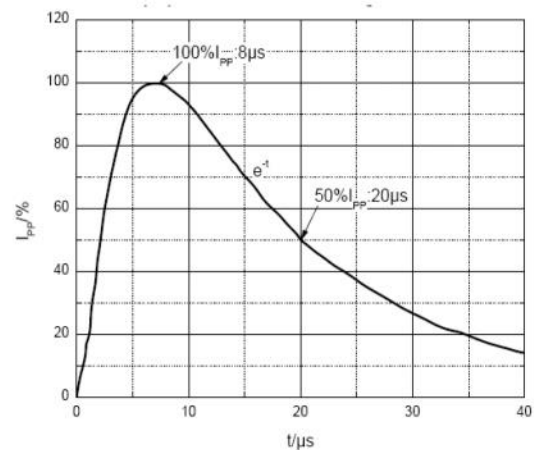
Contact Discharge		Air Discharge	
Level	Test Voltage kV	Level	Test Voltage kV
1	2	1	2
2	4	2	4
3	6	3	8
4	8	4	15

JESD22-A114-B Standard

ESD Class	Human Body Discharge V
0	0~249
1A	250~499
1B	500~999
1C	1000~1999
2	2000~3999
3A	4000~7999
3B	8000~15999



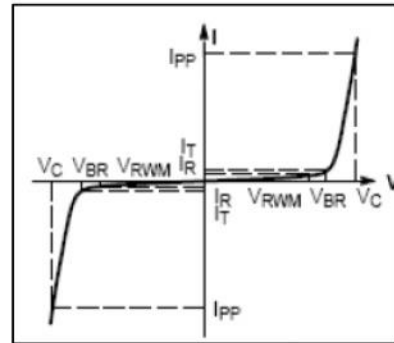
ESD pulse waveform according to IEC61000-4-2



8/20 μs pulse waveform according to IEC 61000-4-5

ELECTRICAL PARAMETER

Symbol	Parameter
V_C	Clamping Voltage @ I_{PP}
I_{PP}	Peak Pulse Current
V_{BR}	Breakdown Voltage @ I_T
I_T	Test Current
I_R	Reverse Leakage Current @ V_{RWM}
V_{RWM}	Reverse Standoff Voltage



V-I characteristics for a Bi-directional TVS

ELECTRICAL CHARACTERISTICS($T_a=25^\circ\text{C}$ unless otherwise specified)

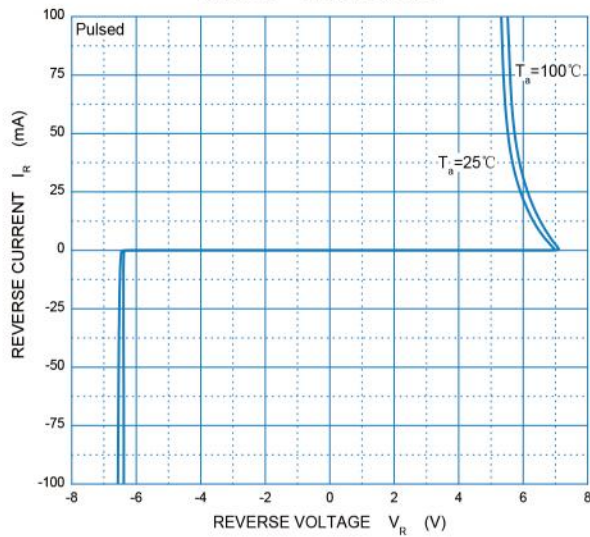
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Reverse stand off voltage	$V_{RWM}^{(1)}$				3.3	V
Reverse leakage current	I_R	$V_{RWM}=3.3\text{V}$			1	μA
Breakdown voltage	$V_{(BR)}$	$I_T=1\text{mA}$	5.8	6.7	7.5	V
Clamping voltage	$V_C^{(2)}$	$I_{PP}=10\text{A}$			15	V
Junction capacitance	C_J	$V_R=0\text{V}, f=1\text{MHz}$		10	15	pF

(1).Other voltages available upon request.

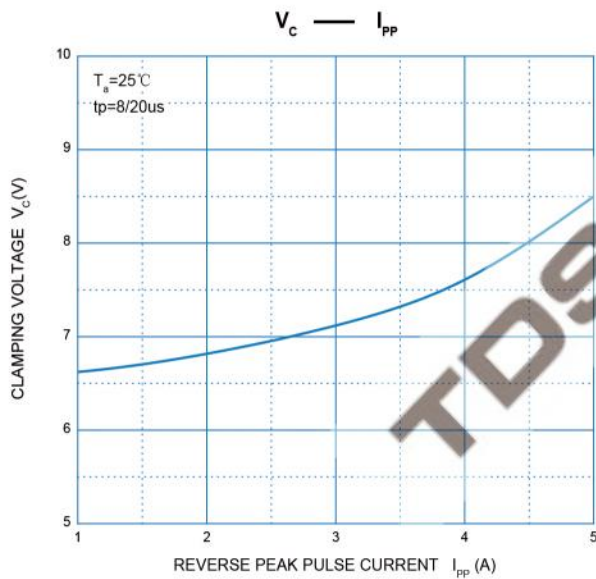
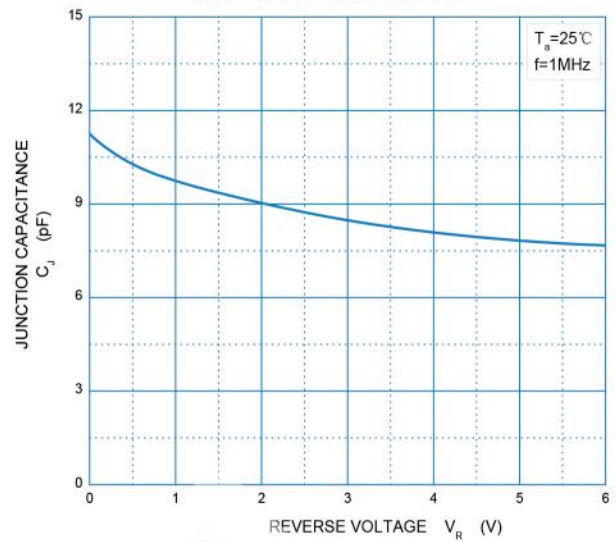
(2).Non-repetitive current pulse 8/20 μs exponential decay waveform according to IEC61000-4-5

TYPICAL CHARACTERISTICS

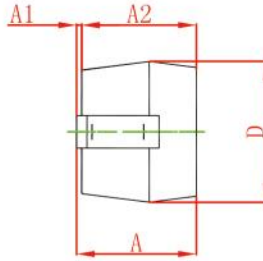
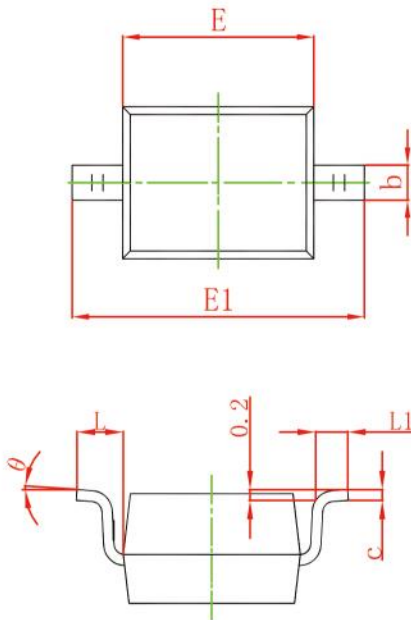
Reverse Characteristics



Capacitance Characteristics

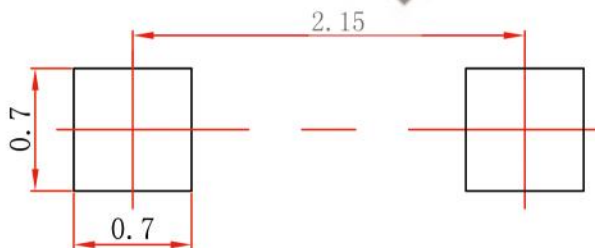


PACKAGE OUTLINE AND PAD LAYOUT INFORMATION SOD-323 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A		1.000		0.039
A1	0.000	0.100	0.000	0.004
A2	0.800	0.900	0.031	0.035
b	0.250	0.350	0.010	0.014
c	0.080	0.150	0.003	0.006
D	1.200	1.400	0.047	0.055
E	1.600	1.800	0.063	0.071
E1	2.550	2.750	0.100	0.108
L	0.475 REF.		0.019 REF.	
L1	0.250	0.400	0.010	0.016
θ	0°	8°	0°	8°

SOD-323 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.